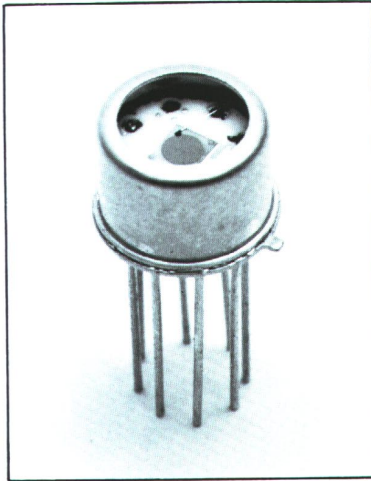




P1-30

Low Noise, Broadband Pyroelectric Detector/Op-Amp

Molelectron
DETECTOR, INCORPORATED

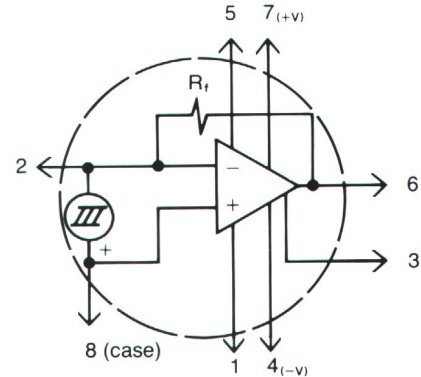
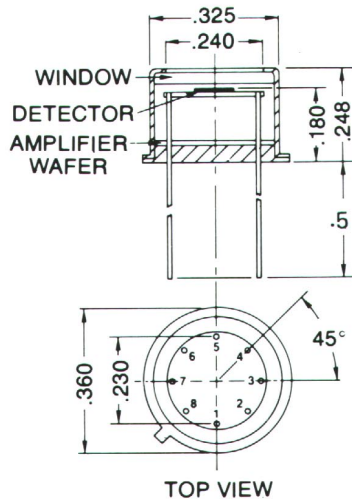
Features

- Rugged LiTaO_3 material
- 610°C Curie temperature
- $0.2\%/^\circ\text{C}$ temperature stability
- Non-hygroscopic
- Broad spectral range .001 to 1000 microns
- Low noise
- 0°C to $+70^\circ\text{C}$ operation
- Optional windows
- High performance operational amplifier
- Flat bandwidth to 3 MHz

Applications

- Laser power and energy measurement
- Non-contact temperature measurement
- Security and surveillance systems
- Process control
- X-ray calorimetry
- Gas analyzer instrumentation
- Solar instrumentation

The P1-30 series features 1, 2, 3, and 5 mm diameter pyroelectric elements with high-performance, wideband hybrid operational amplifiers packaged together in TO-5 transistor cases. With standard internal 10^8 -ohm feedback resistors they deliver high responsivity with 8 kHz flat bandwidth. The internal feedback resistor may be paralleled externally with lower resistances to 10^5 ohms to achieve wider uniform frequency response out to upper-3-dB frequencies as high as 3 MHz. Power supply noise rejection is typically -70 dB when operated from an external ± 15 Vdc source.



Performance Specifications P1-30

CHARACTERISTICS (25°C unless otherwise noted)		P1-31			P1-32			P1-33			P1-35			UNIT	CONDITIONS
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
ELEMENT ONLY															
Dia	Active Diameter	1			2			3			5			mm	
R _i	Current Responsivity	.5	1		.25	.5		.25	.5		.13	.25		μA/Watt	λ = 632.8 nm f ≥ 15 Hz
C _D	Element Capacitance	15			24			54			75			pF	f = 1 kHz
f _T	Thermal 3db Frequency	3.5	6		1.6	3		.8	2		.5	1		Hz	P _{AVG} ≤ 10 mW

ELEMENT AND OP AMP															
R_V	Voltage Responsivity (See Figures 1-4)	50	100		25	50		25	50		13	25		Volts/Watt	$\lambda = 632.8 \text{ nm}$ $f = 1 \text{ kHz}$
NEP	Noise Equivalent Power (See Figures 1-4)	200	400		400	800		400	800		800	1000		$10^{-9} \text{ W/Hz}^{1/2}$	$\lambda = 632.8 \text{ nm}$ $f = 1 \text{ kHz}$ $BW = 1 \text{ Hz}$
D^*	Detectivity	2.2	4.4		2.2	4.4		3.3	6.7		2.8	5.5		$10^8 \text{ cm}^2/\text{Hz}^{1/2}\text{Watt}$	$\lambda = 632.8 \text{ nm}$ $f = 1 \text{ kHz}$ $BW = 1 \text{ Hz}$
f_h	Flat Frequency Response	3M			3M			3M			3M			Hz	External Feedback Resistor
R_S	Internal Feedback Resistor	1			1			1			1			10^8 Ohm	
C_i	Internal Stray Feedback Capacitance	0.2	1.0		0.2	1.0		0.2	1.0		0.2	1.0		pF	
R_O	Output Impedance	100			100			100			100			Ohms	
$P_{MAX \text{ Avg}}$	Maximum Average Power	50			50			50			50			m Watts	
V_{CC}	Supply Voltage	± 15			± 15			± 15			± 15			Volts	
I_{CC}	DC Bias Current	3	4		3	4		3	4		3	4		mA	

Note: 1. R_i , R_V , NEP and D^* are specified at 632.8nm with windowless detector. These parameters improve 30% at $10.6\mu\text{m}$.
2. If CC Black Absorbing Coating is specified R_i , R_V , NEP and D^* can improve by 20 to 40% at all wavelengths. However, this coating limits their use to frequencies $< 100 \text{ Hz}$.

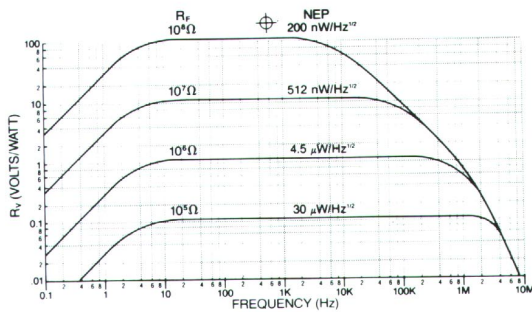


Fig. 1 Plot of typical Responsivity R_V versus Frequency for P1-31 Pyroelectric Detectors with various external feedback resistors.

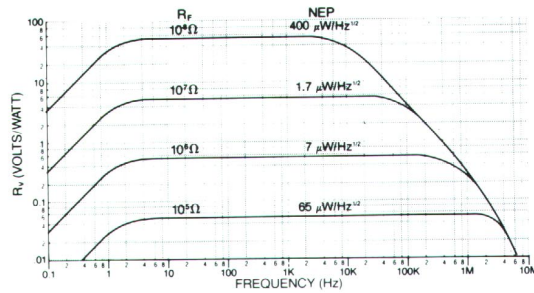


Fig. 2 Plot of typical Responsivity R_V versus Frequency for P1-32 Pyroelectric Detectors with various external feedback resistors.

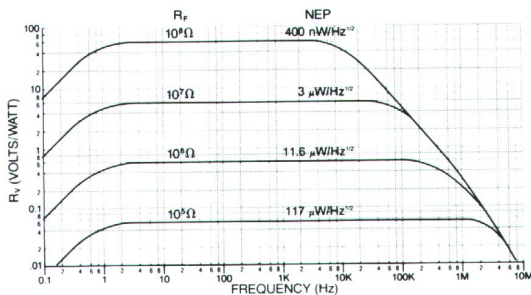


Fig. 3 Plot of typical Responsivity R_V versus Frequency for P1-33 Pyroelectric Detectors with various external feedback resistors.

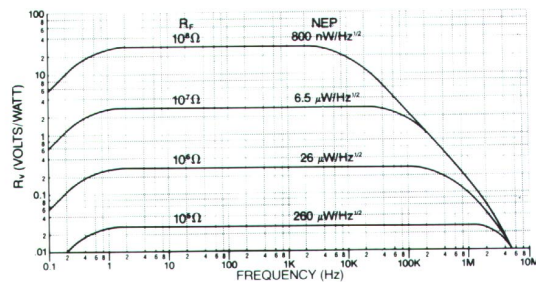
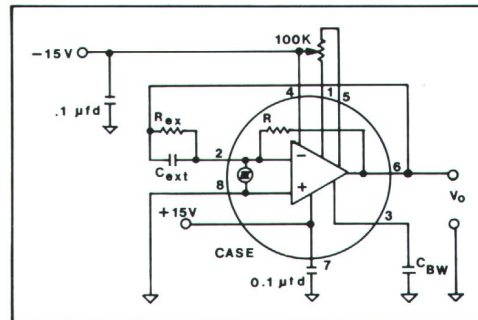


Fig. 4 Plot of typical Responsivity R_V versus Frequency for P1-35 Pyroelectric Detectors with various external feedback resistors.

Typical Circuit Diagram



- Notes: 1. All grounds as short as possible.
2. Offset adjust optional for $R_{T(tot)} \leq 10^9$ ohms.
3. R_{EXT} is an optional external resistor used to achieve wider flat bandwidth with lower voltage responsivity.

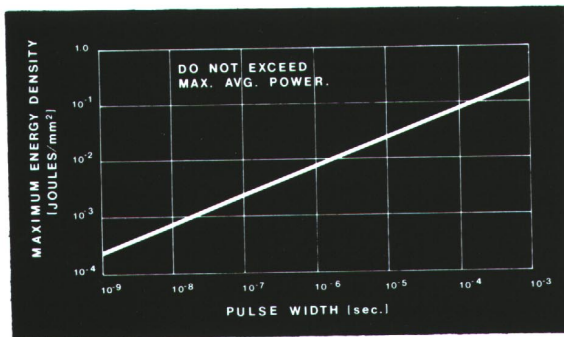


Fig. 5 Relative spectral response vs wavelength

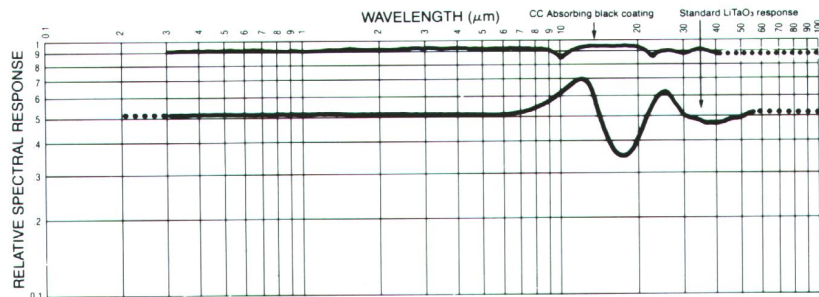


Fig. 6 Relative spectral response vs wavelength